



PRESIDENCY UNIVERSITY

BENGALURU

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Make-up Examinations - December 2025

Date: 27 - 12- 2025

Time: 01:00pm - 04:00pm

School: SOE	Program: B.Tech. (ECE)		
Course Code: ECE3045	Course Name: Sensor Technology		
Semester: MK	Max Marks: 100	Weightage: 50%	

CO - Levels	C01	C02	C03	C04	C05
Marks	24	24	26	26	-

Instructions:

(i) Read all questions carefully and answer accordingly.

(ii) Do not write anything on the question paper other than roll number.

Part A

Answer ALL the Questions. Each question carries 2marks.

10Q x 2M=20M

1	List the any two differences between sensor and transducer	2 Marks	L1	C01
2	With neat diagram, label cut-off and saturation.	2 Marks	L1	C01
3	For capacitance-based sensor, identify the material property and geometric property.	2 Marks	L1	C02
4	Define piezoelectric effect.	2 Marks	L1	C02
5	Write the current-voltage relationship for a photodiode	2 Marks	L1	C03
6	What are the various switching types?	2 Marks	L1	C03
7	Describe "ice-bath" technique used to maintain reference junction in a thermocouple.	2Marks	L1	C03
8	What is the output voltage for a non-inverting amplifier?	2 Marks	L1	C04
9	Draw the transfer characteristics (I-V) for an open-loop op-amp	2 Marks	L1	C04
10	How to find the cut-off frequency for a Notch filter?	2Marks	L1	C04

Part B

Answer the Questions.

Total Marks 80M

11.	a.	Draw the schematic for a measurement system and explain each component of the system	10 Marks	L2	CO1
	b.	With necessary graphs, describe zero drift and sensitivity drift	10 Marks	L2	CO1
Or					
12.	a.	Describe in detail the model used to understand reliability analysis	10 Marks	L2	CO1
	b.	Compare the following: (i) Response time, (ii) Delay time, (iii) Rise time, (iv) Settling time and (v) Peak time.	10 Marks	L2	CO1
Or					
13.	a.	Explain the parameters that could be modified to develop a resistance-based sensor. Describe the dependence of temperature on resistance.	10 Marks	L2	CO1
	b.	Compare the following principles of light sensors: photo-emissive, photo-voltaic and photo-conductive	10 Marks	L2	CO1
Or					
14.	a.	For a piezoelectric sensor, illustrate the relationship between applied pressure and output voltage.	10 Marks	L2	CO1
	b.	Explain all four effects responsible for developing a sensor using thermoelectric effect.	10 Marks	L2	CO1
Or					
15.	a.	With the help of neat figures, show that the Linear Variable Differential Transformer (LVDT) can be used to detect both direction and magnitude.	10 Marks	L2	CO1
	b.	Explain all the three principles by which an object can be detected using photoelectric- based proximity sensor.	10 Marks	L2	CO1
Or					
16.	a.	Explain the construction of a photo-diode and its working when the diode is forward-biased and reverse-biased.	10 Marks	L2	CO1
	b.	Illustrate various techniques by which one of the junctions in a thermocouple is maintained as a reference (cold-junction).	10 Marks	L2	CO1
Or					
17.	a.	The output of a sensor is 0.2mV which is provided to an amplifier. The amplifier is designed using an op-amp with an input resistance of 12k Ω and feedback resistance of 60k Ω . Estimate the output produced by (i) non-inverting amplifier, (ii) inverting amplifier and (iii) buffer amplifier	10 Marks	L3	CO1
	b.	An instrumentation amplifier is developed such that the gain of the first stage is 10 and the gain of the second stage is 100. If the differential input is 25mV, determine the output voltage. If the feedback resistor of the first stage is 2k Ω , calculate the range of the gain resistor, if the gain varies from 5 to 50.	10 Marks	L3	CO1
Or					
18.	a.	Construct a differential amplifier, such that the gain of the amplifier is 100.	10 Marks	L3	CO1
	b.	A sensor produces an output signal with a frequency greater than 40Hz. An electrical interference noise of 60Hz might be incorporated in the output signal. Construct the necessary high-pass filter and notch filter. Assume the value of the resistors to be 1k Ω .	10 Marks	L3	CO1